TAIWAN SEMICONDUCTOR

RoHS COMPLIANCE

TSM6963SD

20V Dual P-Channel MOSFET

TSSOP-8

Pin Definition:

1. Drain 1	8. Drain 2
2. Source 1	7. Source 2
3. Source 1	6. Source 2
4. Gate 1	5. Gate 2

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$(mΩ)	I_D (A)
-20	30 @ V_{GS} = -4.5V	-4.5
	42 @ V_{GS} = -2.5V	-3
	68 @ V_{GS} = -1.8V	-2

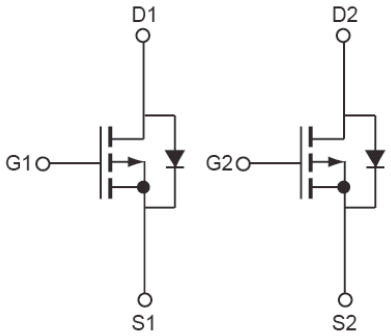
Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switch
- PA Switch

Block Diagram



Dual P-Channel MOSFET

Ordering Information

Part No.	Package	Packing
TSM6963SDCA RV	TSSOP-8	2.5Kpcs / 13” Reel

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	±12	V
Continuous Drain Current, V_{GS} @4.5V.		I_D	-4.5	A
Pulsed Drain Current, V_{GS} @4.5V		I_{DM}	-16	A
Continuous Source Current (Diode Conduction)[a,b]		I_S	-1.0	A
Maximum Power Dissipation	Ta = 25°C	P_D	1.14	W
	Ta = 70°C		0.73	
Operating Junction Temperature		T_J	+150	°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Foot (Drain) Thermal Resistance	$R\Theta_{JF}$	75	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	$R\Theta_{JA}$	90	°C/W

Notes:

a. Surface Mounted on 1” x 1” FR4 Board.

b. Pulse width limited by maximum junction temperature

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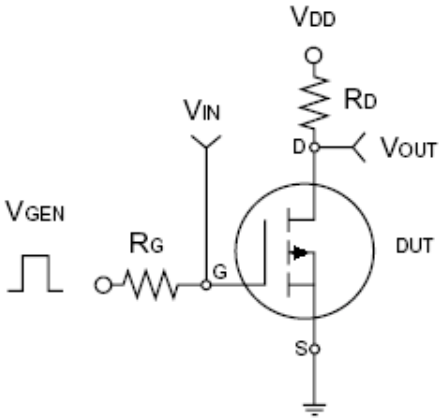
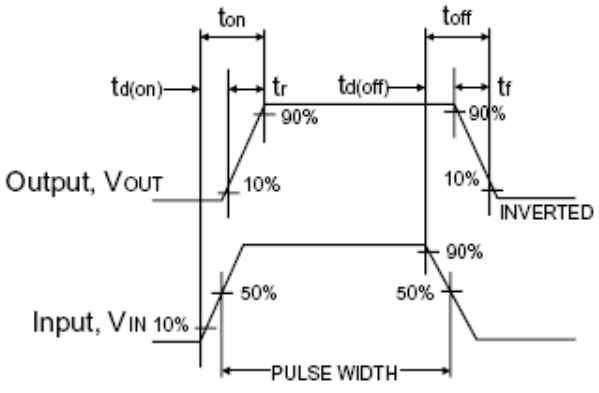
Electrical Specifications (Ta =25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	V_{GS} =0V, I_D =-250uA	BV_{DSS}	-20	--	--	V
Gate Threshold Voltage	V_{DS} =V_{GS}, I_D =-250uA	$V_{GS(TH)}$	-0.5	-0.7	-1.0	V
Zero Gate Voltage Drain Current	V_{DS} =-16V, V_{GS} =0V	I_{DSS}	--	--	-1	uA
Gate Body Leakage	V_{GS} =±12V, V_{DS} =0V	I_{GSS}	--	--	±100	nA
On-State Drain Current	V_{DS} =-5V, V_{GS} =-4.5V	$I_{D(ON)}$	-25	--	--	A
Drain-Source On-State Resistance	V_{GS} =-4.5V, I_D =-4.5A	$R_{DS(ON)}$	--	23	30	mΩ
	V_{GS} =-2.5V, I_D =-3A		--	30	42	
	V_{GS} =-1.8V, I_D =-2A		--	45	68	
Forward Transconductance	V_{DS} =-5V, I_D =-4.5A	g_{fs}	--	16	--	S
Diode Forward Voltage	I_S =-0.5A, V_{GS} =0V	V_{SD}	--	- 0.8	-1.3	V
Dynamic[b]						
Total Gate Charge	V_{DS} =-10V, I_D =-4.5A, V_{GS} =-4.5V	Q_g	--	14	20	nC
Gate-Source Charge		Q_{gs}	--	2.1	10	
Gate-Drain Charge		Q_{gd}	--	4.7	--	
Input Capacitance	V_{DS} =-10V, V_{GS} =0V, f =1.0MHz	C_{iss}	--	1500	--	pF
Output Capacitance		C_{oss}	--	220	--	
Reverse Transfer Capacitance		C_{rss}	--	160	--	
Switching[c]						
Turn-On Delay Time	V_{DD} =-10V, R_L =10Ω, I_D =-1A, V_{GEN} =-4.5V, R_G =6Ω	$t_{d(on)}$	--	6	11	nS
Turn-On Rise Time		t_r	--	13	23	
Turn-Off Delay Time		$t_{d(off)}$	--	86	145	
Turn-Off Fall Time		t_f	--	42	70	

Notes:
a. pulse test: PW ≤300μS, duty cycle ≤2%
b. For DESIGN AID ONLY, not subject to production testing.
b. Switching time is essentially independent of operating temperature.



Switching Test Circuit



Switchin Waveforms

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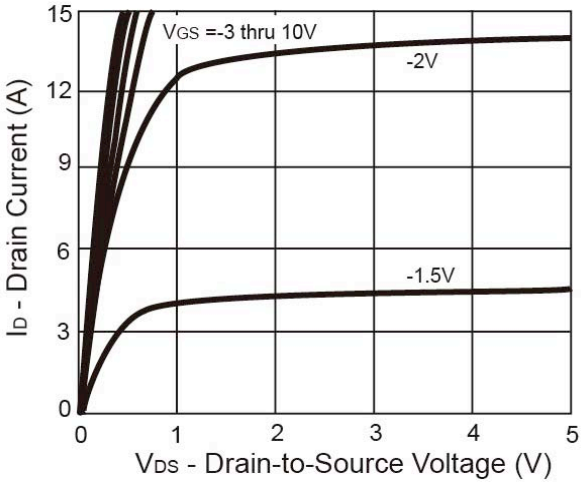
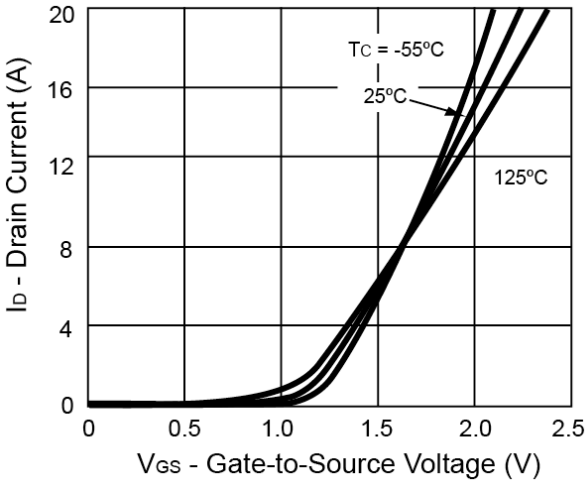
Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

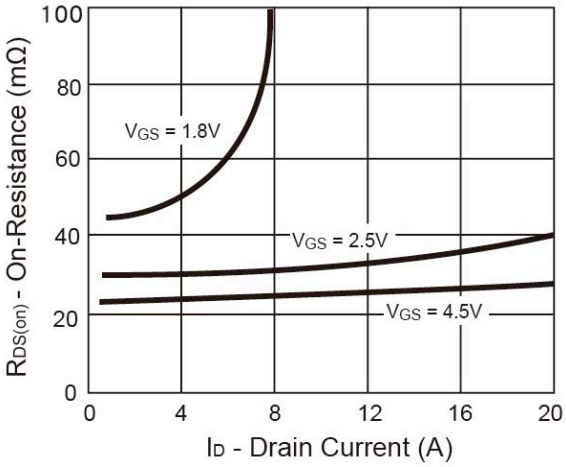
Output Characteristics



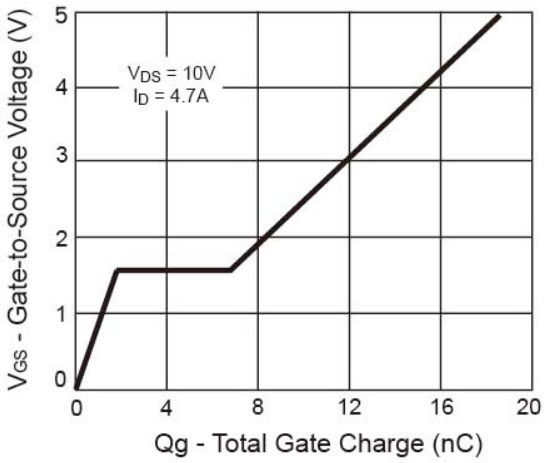
Transfer Characteristics



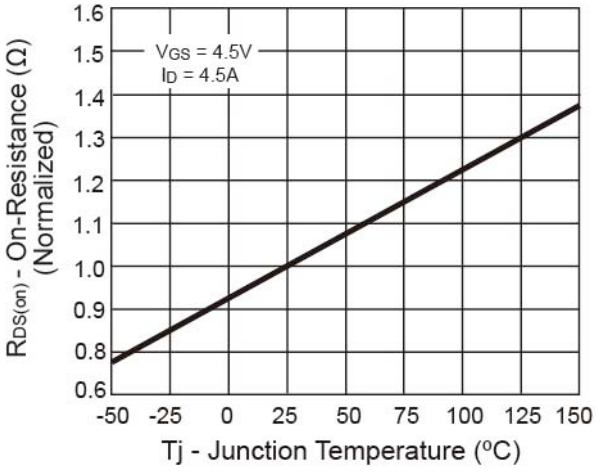
On-Resistance vs. Drain Current



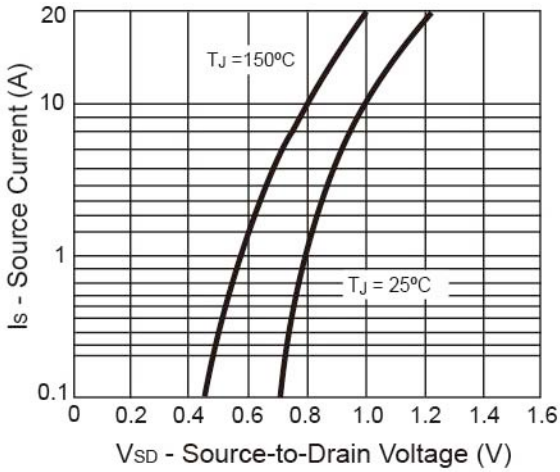
Gate Charge



On-Resistance vs. Junction Temperature

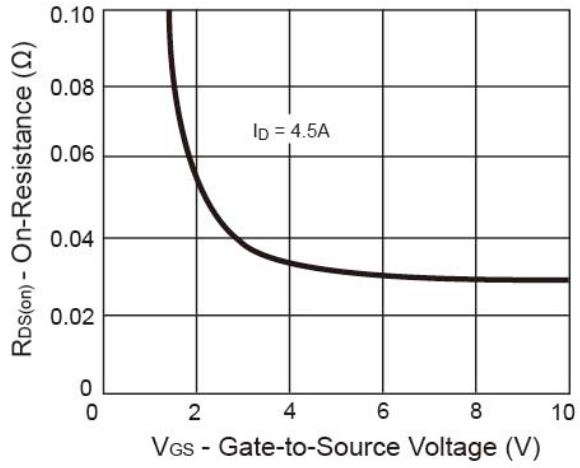


Source-Drain Diode Forward Voltage

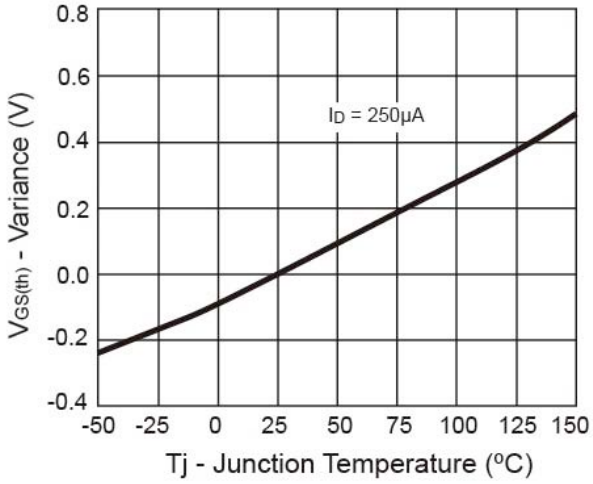


Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

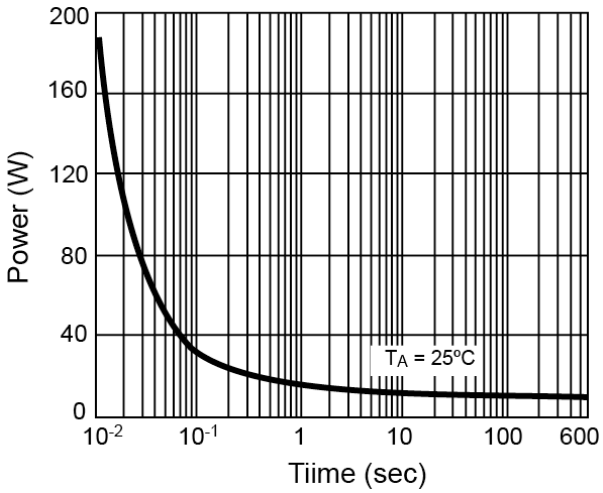
On-Resistance vs. Gate-Source Voltage



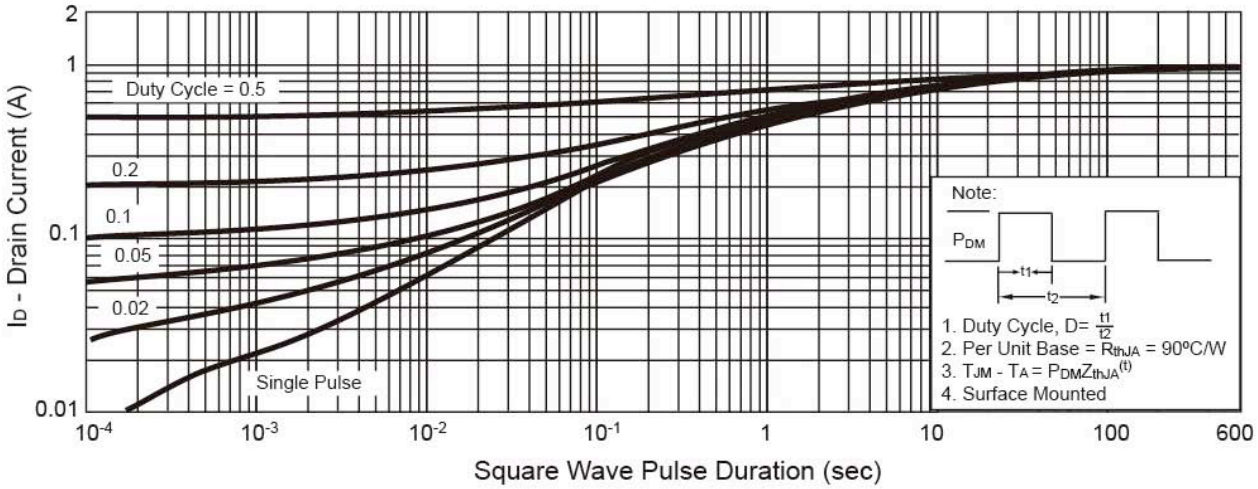
Threshold Voltage



Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient



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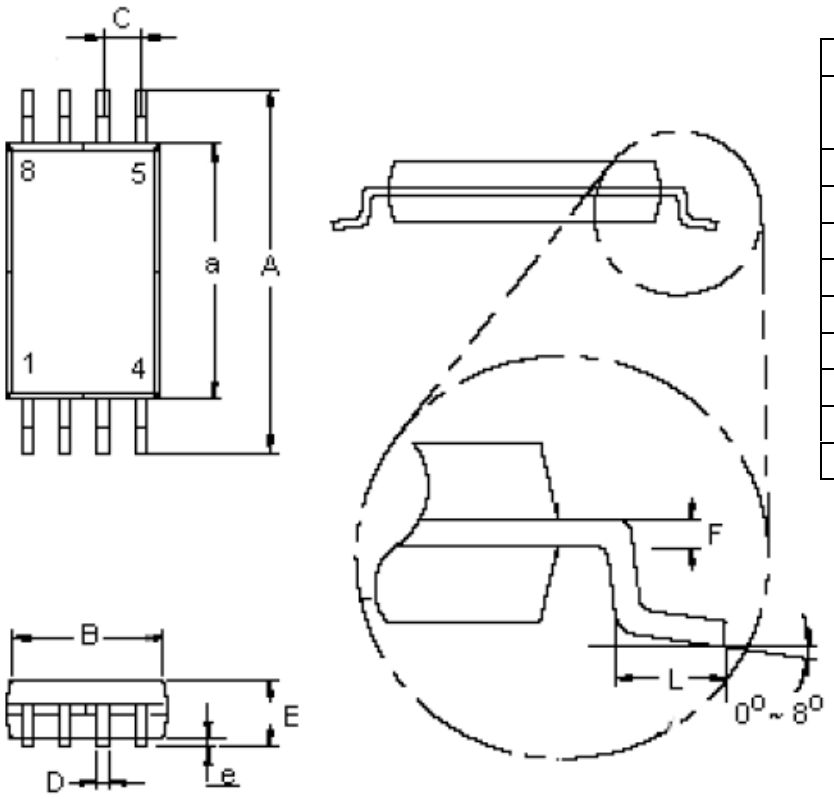
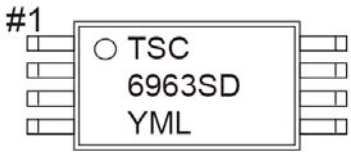
TSSOP-8 Mechanical Drawing



TSSOP-8 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	6.20	6.60	0.244	0.260
a	4.30	4.50	0.170	0.177
B	2.90	3.10	0.114	0.122
C	0.65 (typ)		0.025 (typ)	
D	0.25	0.30	0.010	0.019
E	1.05	1.20	0.041	0.049
e	0.05	0.15	0.002	0.009
F	0.127		0.005	
L	0.50	0.70	0.020	0.028

Marking Diagram



Y = Year Code

M = Month Code
(**A**=Jan, **B**=Feb, **C**=Mar, **D**=Apl, **E**=May, **F**=Jun, **G**=Jul, **H**=Aug, **I**=Sep, **J**=Oct, **K**=Nov, **L**=Dec)

L = Lot Code

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